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July 2000



### FDC6327C

#### Dual N & P-Channel 2.5V Specified PowerTrench<sup>™</sup> MOSFET

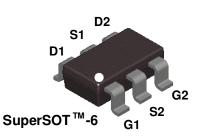
#### **General Description**

These N & P-Channel 2.5V specified MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain low gate charge for superior switching performance.

These devices have been designed to offer exceptional power dissipation in a very small footprint for applications where the bigger more expensive SO-8 and TSSOP-8 packages are impractical.

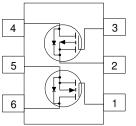
#### Applications

- DC/DC converter
- · Load switch
- Motor driving



#### Features

- N-Channel 2.7A, 20V.  $R_{DS(on)} = 0.08\Omega$  @  $V_{GS} = 4.5V$  $R_{DS(on)} = 0.12\Omega$  @  $V_{GS} = 2.5V$
- + P-Channel -1.6A, -20V.R $_{\rm DS(on)}$  = 0.17 $\Omega$  @ V $_{\rm GS}$  = -4.5V  $\rm R_{\rm DS(on)}$ = 0.25 $\Omega$  @ V $_{\rm GS}$  = -2.5V
- Fast switching speed.
- · Low gate charge.
- High performance trench technology for extremely low  $\rm R_{\rm DS(ON)}.$
- SuperSOT<sup>™</sup>-6 package: small footprint (72% smaller than SO-8); low profile (1mm thick).



#### Absolute Maximum Ratings $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		N-Channel	P-Channel	Units
V <sub>DSS</sub>	Drain-Source Voltage		20	-20	V
V <sub>GSS</sub>	Gate-Source Voltage		<u>+</u> 8	<u>+</u> 8	V
ID	Drain Current - Continuous	(Note 1a)	2.7	-1.9	А
	- Pulsed		8	-8	
P <sub>D</sub>	P <sub>D</sub> Power Dissipation (Note 1		0.9	W	
		(Note 1b)	0.	9	
		(Note 1c)	0.	7	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range		-55 to	+150	°C
Therma	I Characteristics				
R <sub>θJA</sub>	Thermal Resistance, Junction-to-Ambient (Note 1a)		130		°C/W
R <sub>θJC</sub>	Thermal Resistance, Junction-to-Case	(Note 1)	6	0	∘C/W

#### Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity		
.327	FDC6327C	7"	8mm	3000		

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Symbol	Parameter	Test Conditions	Type	Min	Түр	Max	Units
Symbol	Falametei	Test Conditions	Type		тур	Ινιάλ	Units
Off Cha	racteristics						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$ $V_{GS} = 0 V, I_D = -250 \mu A$	N-Ch P-Ch	20 -20			V
<u>A</u> BVdss ATJ	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C $I_D = -250 \ \mu$ A, Referenced to 25°C	N-Ch P-Ch		12 -19		mV/∘C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 16 V, V_{GS} = 0 V$ $V_{DS} = -16 V, V_{GS} = 0 V$	N-Ch P-Ch			1 -1	μA
I <sub>GSSF</sub>	Gate-Body Leakage, Forward	$V_{GS} = 8 V, V_{DS} = 0 V$	All			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage, Reverse	$V_{GS} = -8 V, V_{DS} = 0 V$	All			-100	nA
On Chai V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	N-Ch P-Ch	0.4	0.9	1.5 -1.5	V
<u>AVGS(th)</u> ΔT.I	Gate Threshold Voltage Temperature Coefficient	$V_{DS} = V_{GS}, I_D = -250 \ \mu\text{A}$ $I_D = 250 \ \mu\text{A}, \text{ Referenced to } 25^{\circ}\text{C}$ $I_D = -250 \ \mu\text{A}, \text{ Referenced to } 25^{\circ}\text{C}$	N-Ch P-Ch	-0.4	-0.9 -2.1 2.3	-1.5	mV/∘C
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance		N-Ch N-Ch P-Ch P-Ch P-Ch P-Ch		0.069 0.094 0.093 0.141 0.203 0.205	0.08 0.13 0.12 0.17 0.27 0.25	Ω
I <sub>D(on)</sub>	On-State Drain Current	$V_{GS} = 4.5 V, V_{DS} = 5 V$ $V_{GS} = -4.5 V, V_{DS} = -5 V$	N-Ch P-Ch	8 -8			A
	Forward Transconductance	$V_{DS} = 5 \text{ V}, I_{D} = 2.7 \text{ A}$	N-Ch		7.7		S

#### **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	N-Channel $V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz}$	N-Ch P-Ch	325 315	pF
C <sub>oss</sub>	Output Capacitance	P-Channel	N-Ch P-Ch	75	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, \text{ f} = 1.0 \text{ MHz}$	N-Ch P-Ch	35	pF

FDC6327C, Rev. E

FDC6327C

Electrical Characteristics (continued) T <sub>A</sub> = 25°C unless otherwise noted							
Symbol	Parameter	Test Conditions	Туре	Min	Түр	Max	Units
Switchir	ng Characteristics (Note	2)					
t <sub>d(on)</sub>	Turn-On Delay Time	N-Channel $V_{DD} = 10 \text{ V}, I_D = 1 \text{ A},$	N-Ch P-Ch		5 7	15 14	ns
t <sub>r</sub>	Turn-On Rise Time	P-Channel V <sub>DD</sub> = -10 V, I <sub>D</sub> = -1 A, V <sub>GS</sub> = -4.5 V, R <sub>GEN</sub> = 6 Ω	N-Ch P-Ch		9 14	18 25	ns
$t_{d(\text{off})}$	Turn-Off Delay Time		N-Ch P-Ch		12 14	22 25	ns
t <sub>f</sub>	Turn-Off Fall Time		N-Ch P-Ch		3 3	9 9	ns
Q <sub>g</sub>	Total Gate Charge	N-Channel $V_{DS} = 10 \text{ V}, I_D = 2.7 \text{ A}, V_{GS} = 4.5 \text{ V}$	N-Ch P-Ch		3.25 2.85	4.5 4.0	nC
$Q_{gs}$	Gate-Source Charge	P-Channel	N-Ch P-Ch		0.65 0.68		nC
$Q_{gd}$	Gate-Drain Charge	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1.9 \text{ A}, \text{V}_{GS} = -4.5 \text{ V}$	N-Ch P-Ch		0.90 0.65		nC

#### **Drain-Source Diode Characteristics and Maximum Ratings**

Is	Maximum Continuous Drain-Source Diode Forward Current	N-Ch P-Ch		0.8 -0.8	A
V <sub>SD</sub>	Drain-Source Diode Forward $V_{GS} = 0 V$ , $I_S = 0.8 A$ (Note 2)	N-Ch	0.76	1.2	V
	Voltage V <sub>GS</sub> = 0 V, I <sub>S</sub> = - 0.8 A (Note 2)	P-Ch	-0.79	-1.2	

#### Notes:

1: R<sub>6JA</sub> is the sum of the junction-to-case and case-to-ambient resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>BJC</sub> is guaranteed by design while R<sub>BJA</sub> is determined by the user's board design. Both devices are assumed to be operating and sharing the dissipated heat energy equally.



a) 130 °C/W when mounted on a 0.125 in<sup>2</sup> pad of 2 oz. copper.



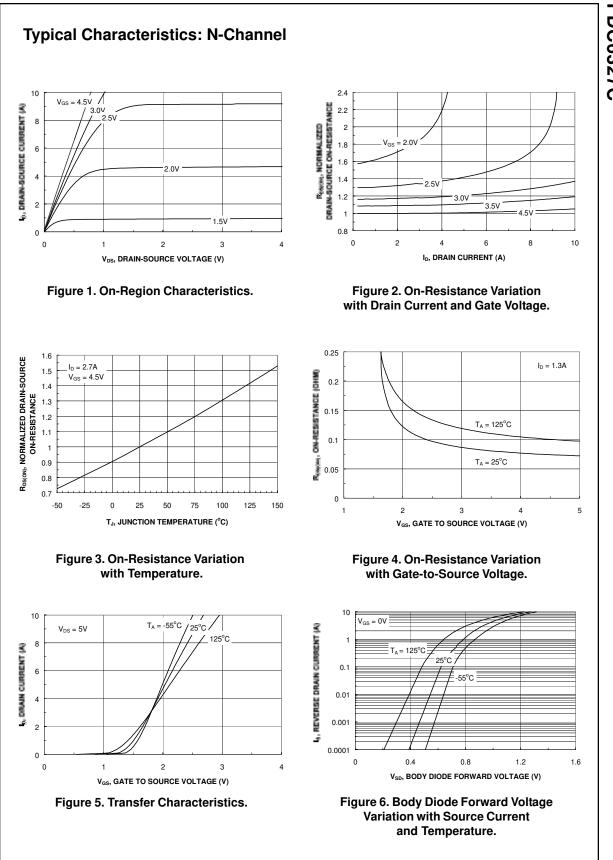
b) 140 °C/W when mounted on a 0.005 in<sup>2</sup> pad of 2 oz. copper.



c) 180 °C/W when mounted on a 0.0015 in<sup>2</sup> pad of 2 oz. copper.

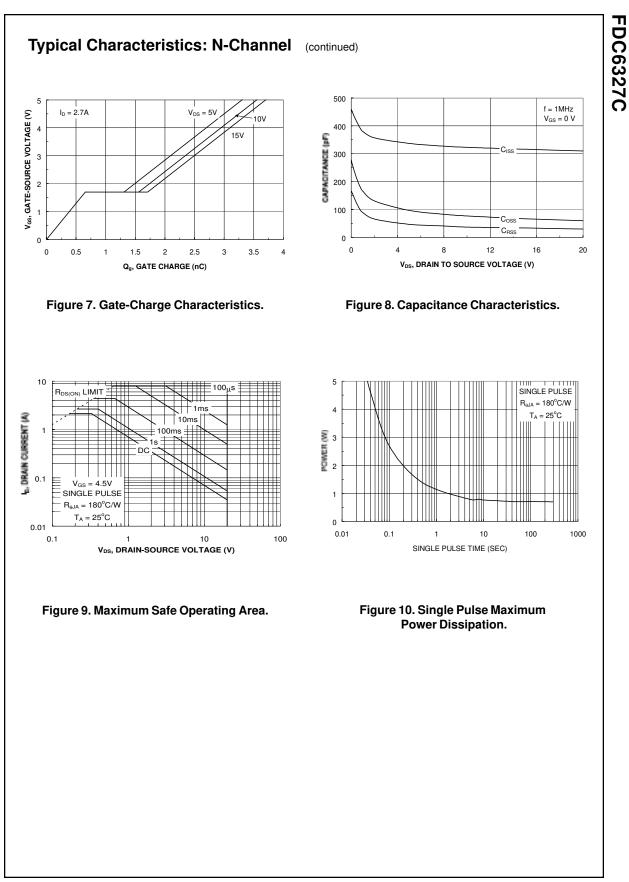
Scale 1:1 on letter size paper

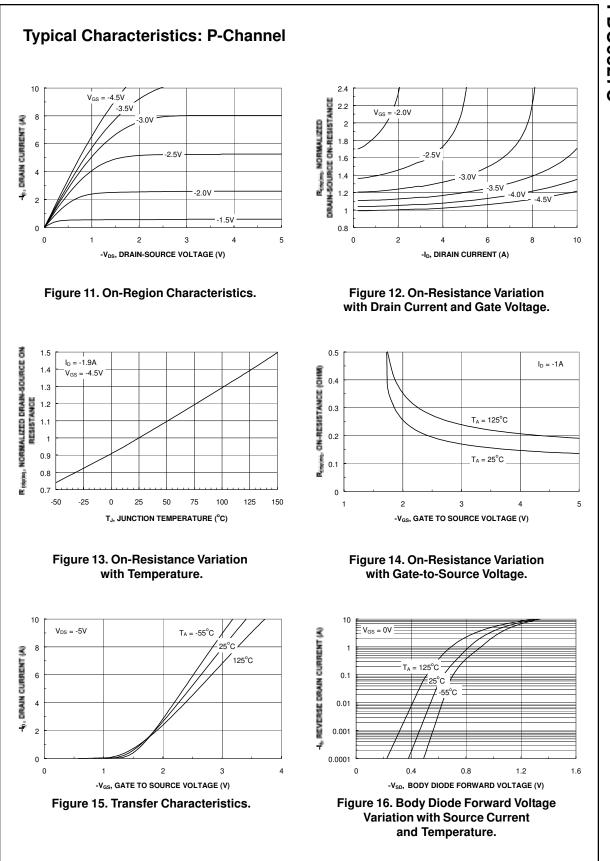
2: Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%



FDC6327C, Rev. E

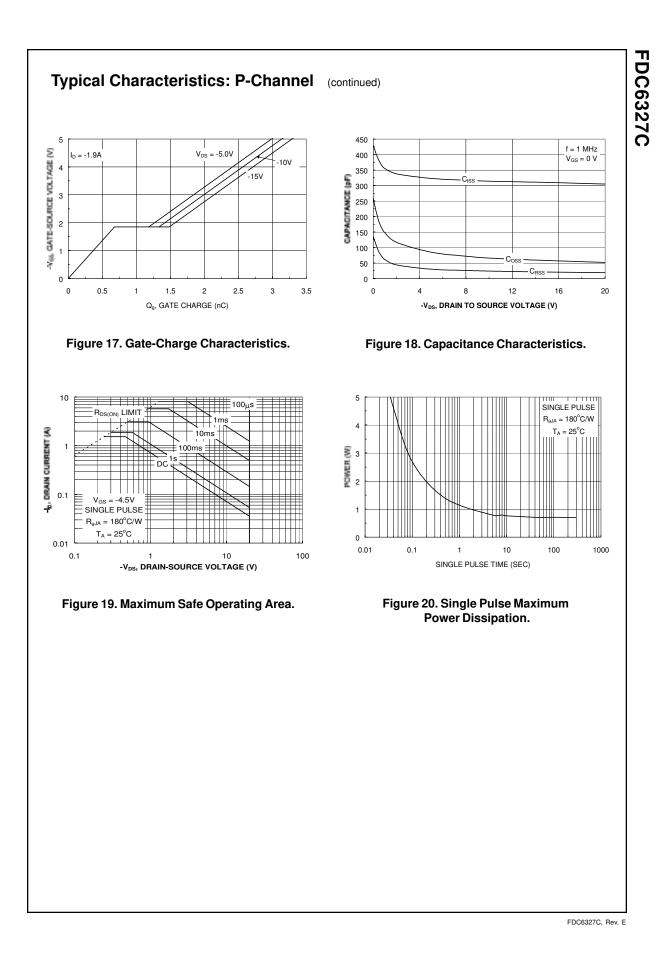
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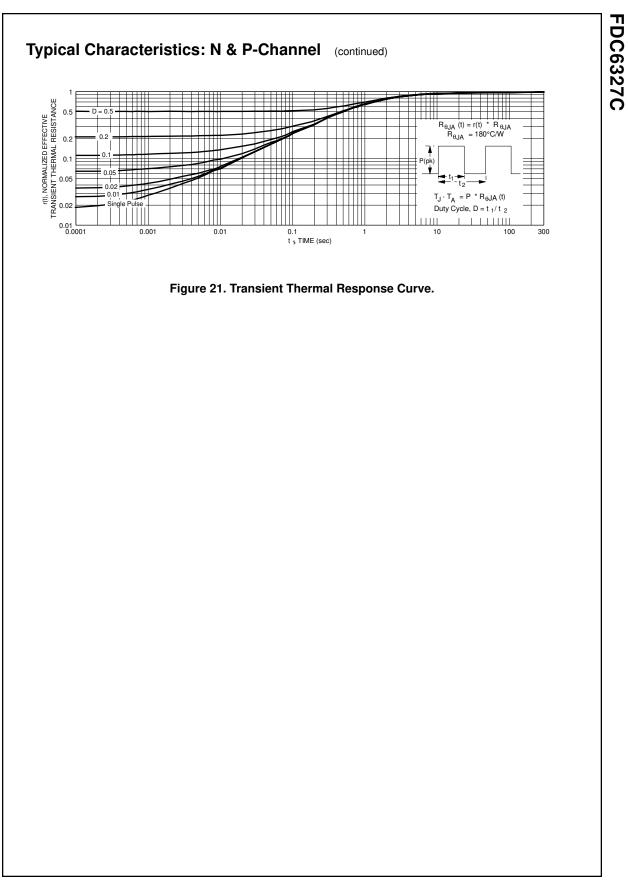




FDC6327C, Rev. E

# FDC6327C





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